



Docket No.: 4066 USA D1/Consilium/Consilium (PATENT)

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of: John F. Arackaparambil et al.

Application No.: 10/084,092

Filed: February 28, 2002

Art Unit: 2125

For: COMPUTER INTEGRATED

MANUFACTURING TECHNIQUES

Examiner: Steven R. Garland

Commissioner for Patents P.O. Box 1450

Alexandria, VA 22313-1450

RESUBMISSION OF UNACKNOWLEDGED REFERENCES

In response to the Examiner's statement in his Office Action of October 17, 2005, that the Information Disclosure Statement filed December 18, 2003, contained references without publication dates, please find attached a new PTO Form SB-08 containing the appropriate date information. A copy of each of these references is also attached.

In response to Examiner's statement that the Information Disclosure Statement filed April 25, 2003, did not contain required documentation of the references, attorney for the applicant herewith provides an additional copy of the references as submitted on April 25, 2003 (as well as a copy of the stamped postcard indicating previous submission of the references). A clean copy of the Form PTO-1449 is herewith attached.

Applicants respectfully request that the Examiner acknowledge these references on the appropriate forms and return them with the next official action. Any deficiency should be charged to Deposit Account No. 08-0219.

Dated: May 17, 2006

Respectfully submitted,

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PTO/SB/08a/b (07-05)
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Substitute for form 1449A/B/PTO				Complete if Known			
			•	Application Number	10/084,092		
١N	IFORMATIO	N DIS	CLOSURE	Filing Date	February 28, 2002		
S	TATEMENT	BY A	PPLICANT	First Named Inventor	Arackaparambil et al.		
				Art Unit	2125		
	(Use as many s	sheets as i	necessary)	Examiner Name	Steven Garland		
Sheet	1	of	1	Attorney Docket Number	4066 USA D1/Consilium/Consilium		

U.S. PATENT DOCUMENTS							
Examiner Initials*	Cite No.1	Document Number Number-Kind Code ² (if known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear		

FOREIGN PATENT DOCUMENTS								
Examiner Initials*	Cite No.1	Foreign Patent Document Country Code ³ -Number ⁴ -Kind Code ⁵ (<i>if known</i>)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	T®		
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*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant. ¹ Applicant's unique citation designation number (optional). ² See Kinds Codes of USPTO Patent Documents at www.uspto.gov or MPEP 901.04. ³ Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). ¹ For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. ⁵ Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST.16 if possible. ⁶ Applicant is to place a check mark here if English language Translation is attached.

	NON PATENT LITERATURE DOCUMENTS								
Examiner Initials	Cite No.1	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T²						
		"NanoMapper wafer nanotopography measurement by ADE Phase Shift." http://www.phase-shift.com/nanomap.shtml. December 9, 2003.							
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Examiner	Date
Signature	Considered
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Applicant's unique citation designation number (optional). ²Applicant is to place a check mark here if English language Translation is attached.

HALE and DORR LLP 1455 Pennsylvania Avenue, NW Washington, DC 20004 (202) 942-8400



Applicant(s):

John F. ARACKAPARAMBIL et al.

Application No.: 10/084,092

Filing Date: February 28, 2002 Docket No.: 004066 USA D01/Consilium/Consilium

Entitled:

Computer Integrated Manufacturing Techniques

107262.169 SMA/AHK/lrm

RECEIPT IS ACKNOWLEDGED FOR THE FOLLOWING:

[X] Supplemental Information Disclosure Statement and 11 PTO-1449 Forms

[X] 213 References in 5 volumes

SHEET 1 OF 11

INFORMATION DISCLOSURE CITATION IN AN APPLICATION (PTO-1449) ATTY. DOCKET NO. 004066 USA D01/Consilium/Consilium SERIAL NO. 10/084,092

APPLICANT

John F. ARACKAPARAMBIL et al.

FILING DATE February 28, 2002 GROUP 2121

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SHEET 2 OF 11

INFORMATION DISCLOSURE CITATION IN AN APPLICATION (PTO-1449)

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Mendez et al.

Matsushita et al.

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APPLICANT

John F. ARACKAPARAMBIL et al.

FILING DATE February 28, 2002 GROUP 2121

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					0020=	Yes	No
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SHEET <u>7</u> OF <u>11</u>

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SHEET 8 OF 11

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